

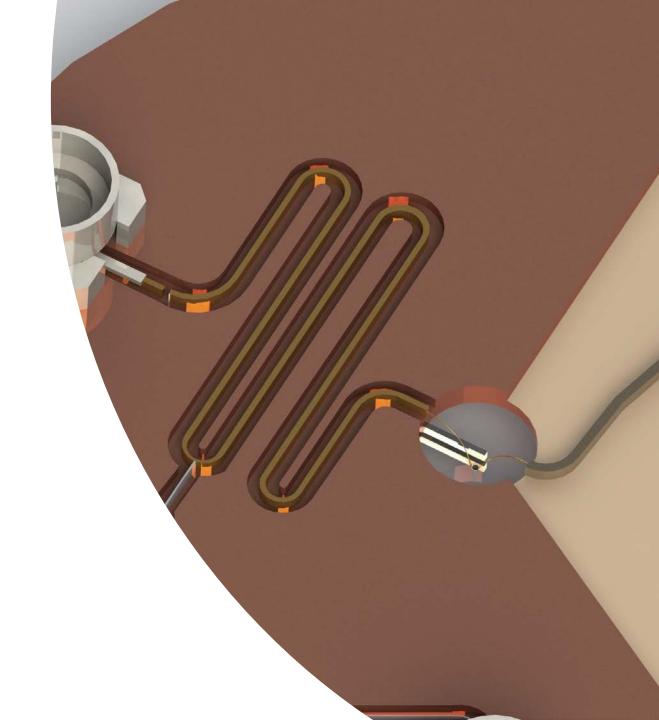
微波阻抗显微镜的搭建及改进

The Construction and Improvement of a Microwave Impedance Microscope

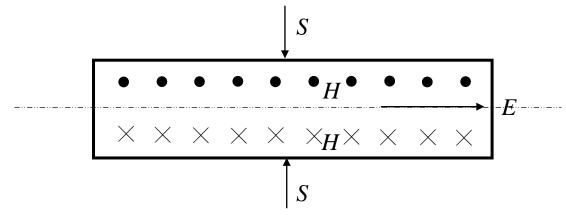
06/10/2020

裴宇翔

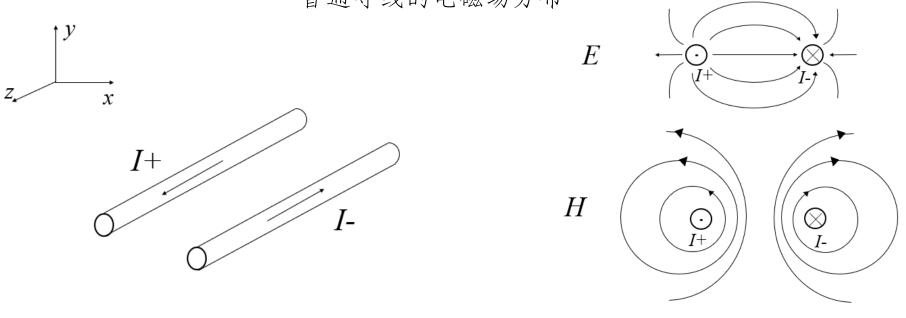
- 微波电路基础
- 微波探测原理
- 微波阻抗显微系统



普通导线与传输线



普通导线的电磁场分布

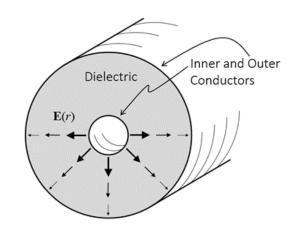


双导线模型

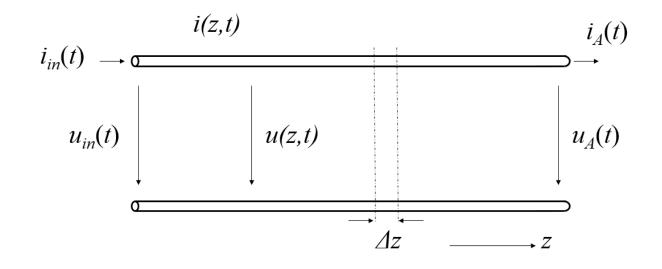
双导线横截面内的电场磁场分布



传输线上的电压和电流



同轴线的中心导体和外部导体

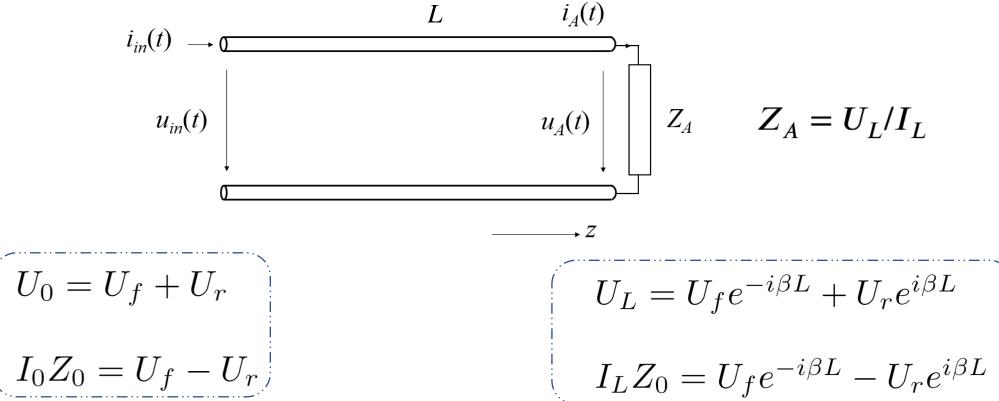


前向波 后向波
$$U(z) = U_f e^{-\gamma z} + U_r e^{\gamma z}$$

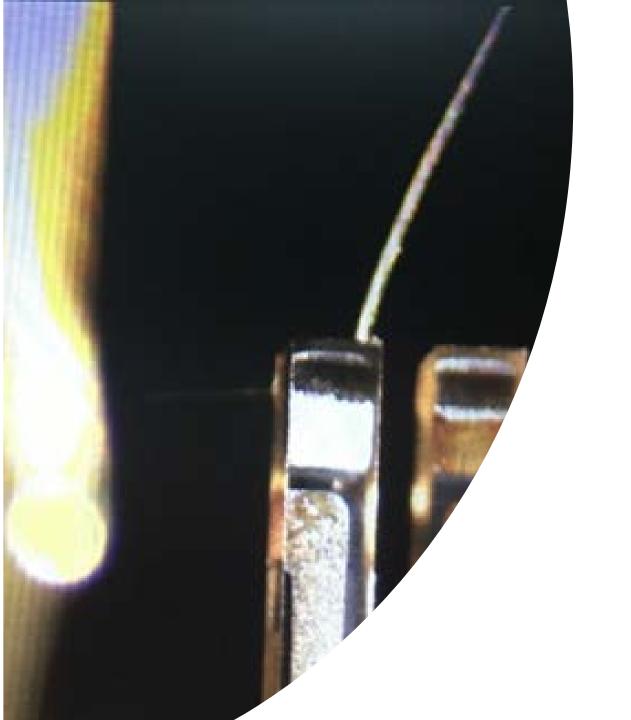
$$I(z)Z_0 = U_f e^{-\gamma z} - U_r e^{\gamma z}$$
特征阻抗



带负载的传输线



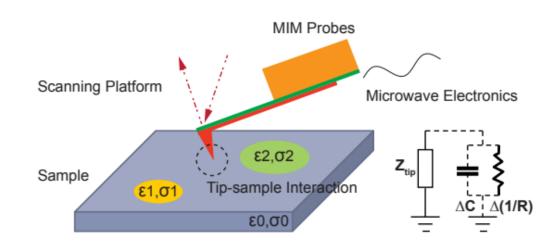
反射系数
$$\Gamma(L) = \frac{U_r e^{i\beta L}}{U_f e^{-i\beta L}} = \Gamma(0)e^{-2i\beta L} = \frac{Z_A - Z_0}{Z_A + Z_0}$$



- 微波电路基础
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共振匹配单元



MIM 测头部分示意图

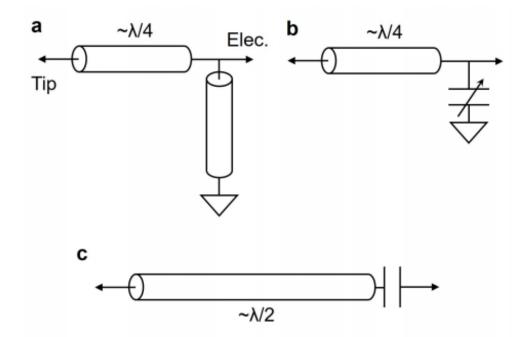
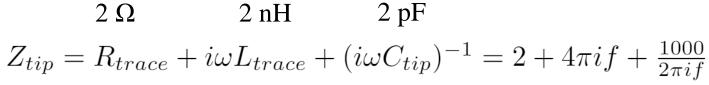
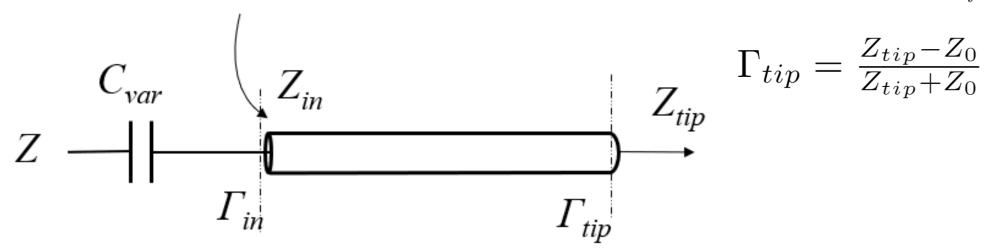


Figure 1.8. (a,b) Single-stub and lumped-element impedance matching networks for shielded cantilever probes. (c) Half-wavelength resonator matching network for TF-based sensors.



共振匹配单元的传输线模型





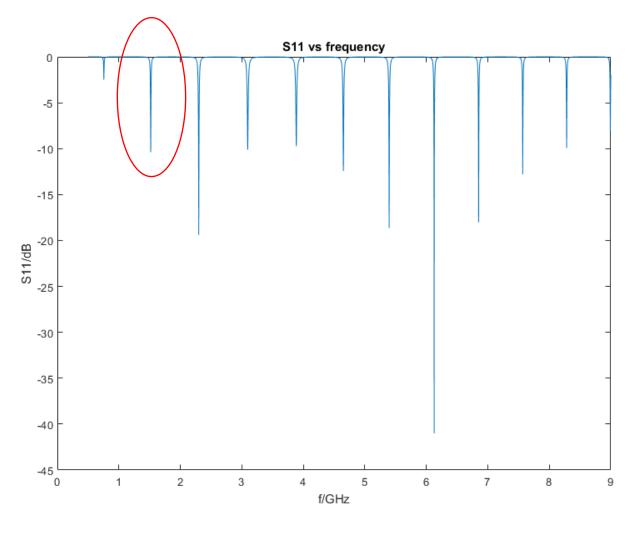
$$\Gamma_{in} = \Gamma_{tip} e^{-2i\beta L}$$

$$Z = Z_{in} + (i\omega C_{var})^{-1} = \frac{1+\Gamma_{in}}{1-\Gamma_{in}} + \frac{1000}{2\pi i f C_{var}}$$

$$S_{11} = \frac{Z - Z_0}{Z + Z_0}$$



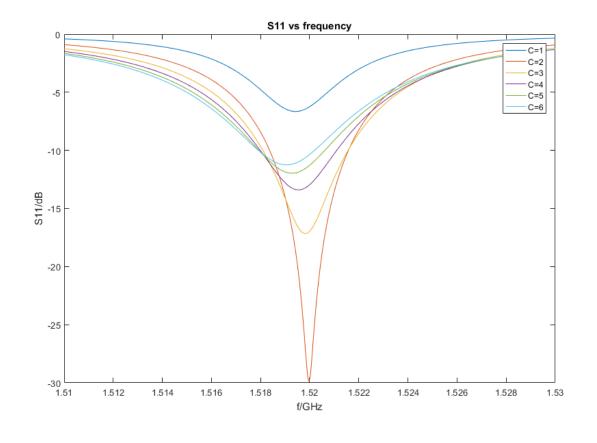
全频段共振峰分布

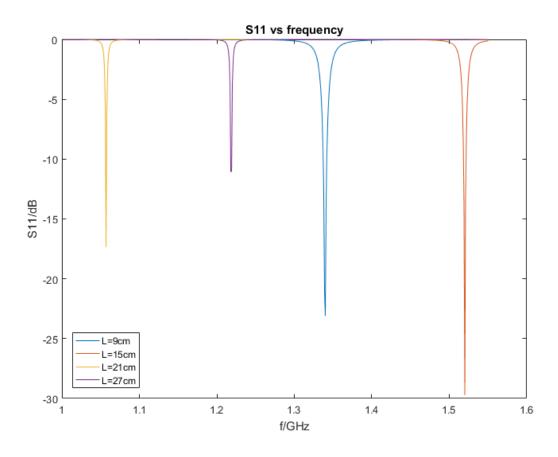


S₁₁ 关于频率 f 的图像(C=9 pF, L=15 cm)



共振峰随参数变化



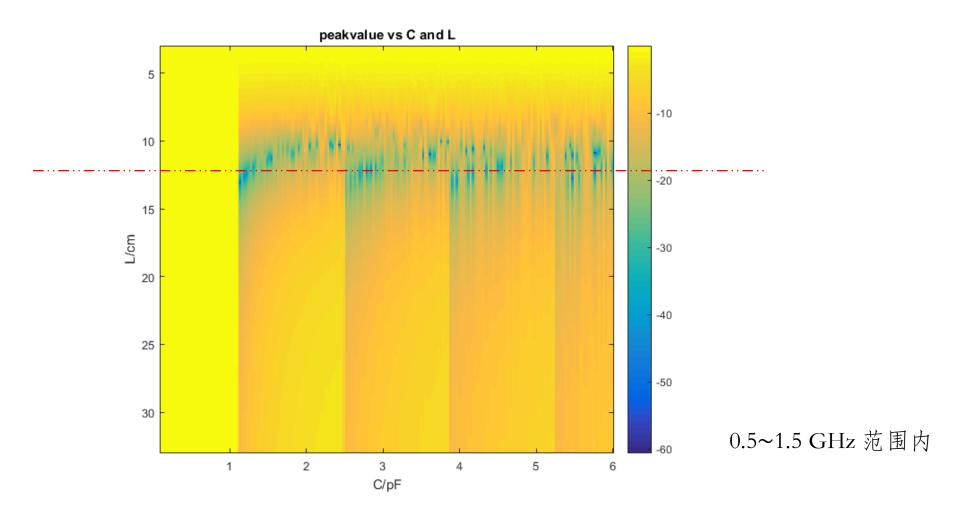


变化电容C

变化长度L



共振峰值关于C&L二维热图



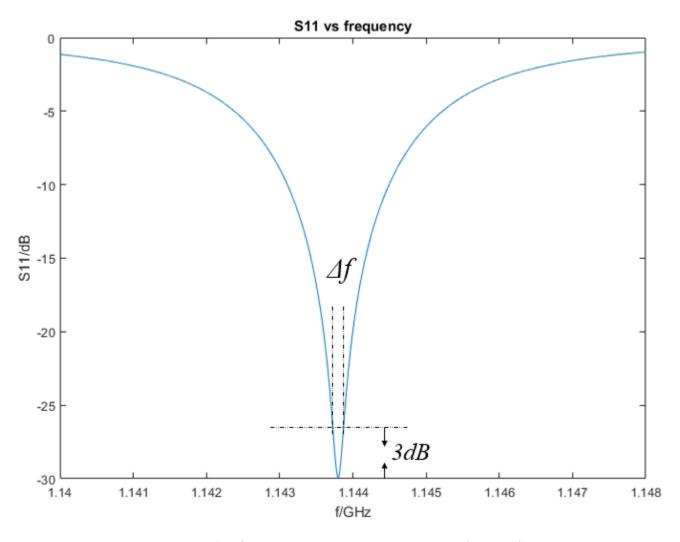
峰值关于可调电容C与传输线长度L的二维热图



共振峰对样品的响应

L = 19.5 cm
$$C_{Var} = 1.8 \text{ pF}$$

$$Q = \frac{1143.8MHz}{0.132MHz} = 8665$$



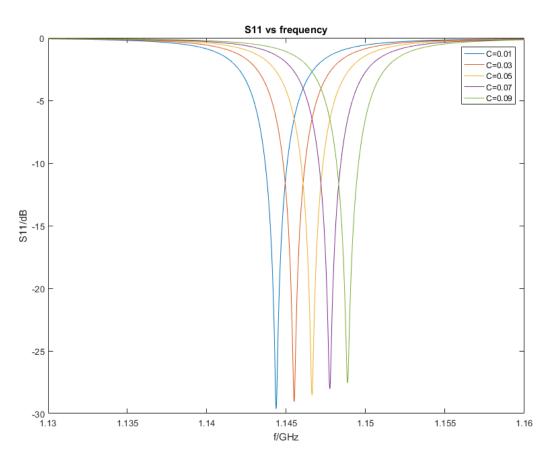
系统在 1.14 GHz 附近的共振峰

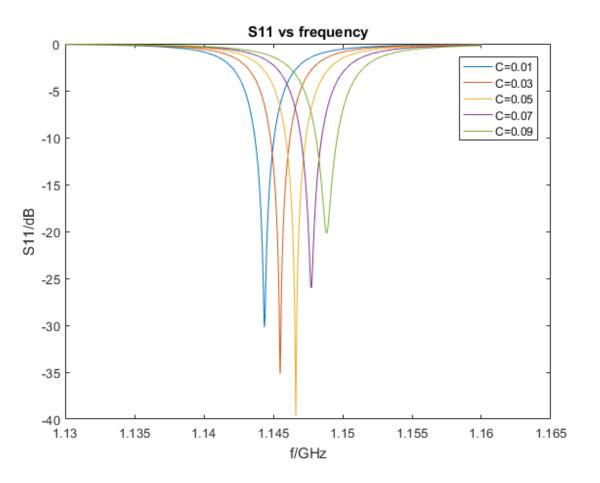


共振峰对样品电容的响应

$$Z_{sample} = R_{sample} + C_{sample} + L_{sample}$$

$$Z_{total} = (\frac{1}{Z_{tip}} + \frac{1}{Z_{sample}})^{-1} = (\frac{1}{Z_{tip}} + \frac{1}{R_s + i\omega L_s + (i\omega C_s)^{-1}})^{-1}$$



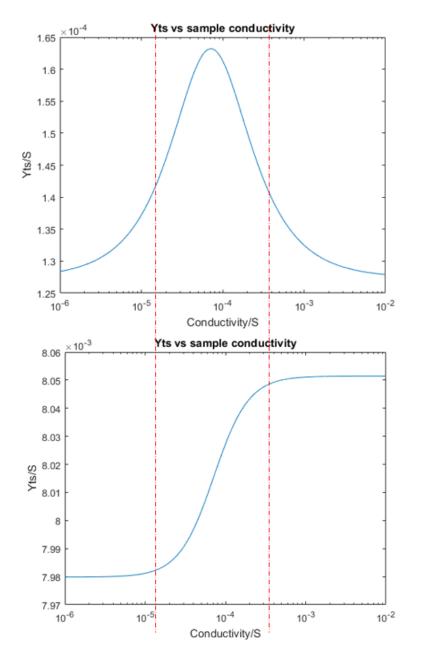


变化Cs (Rs=0)

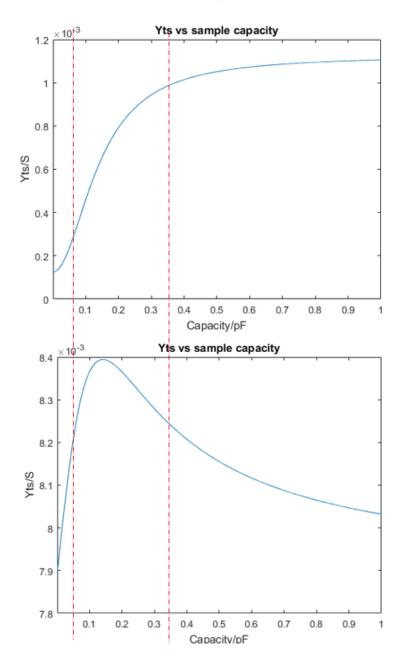
变化Cs (Rs=100 Ω)



电阻灵敏窗口

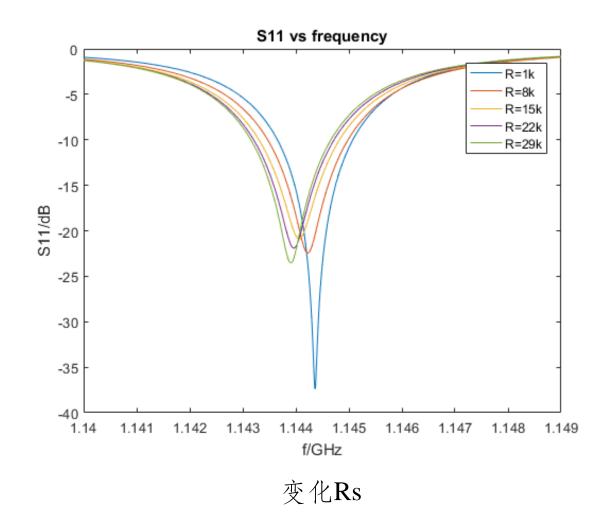


电容灵敏窗口





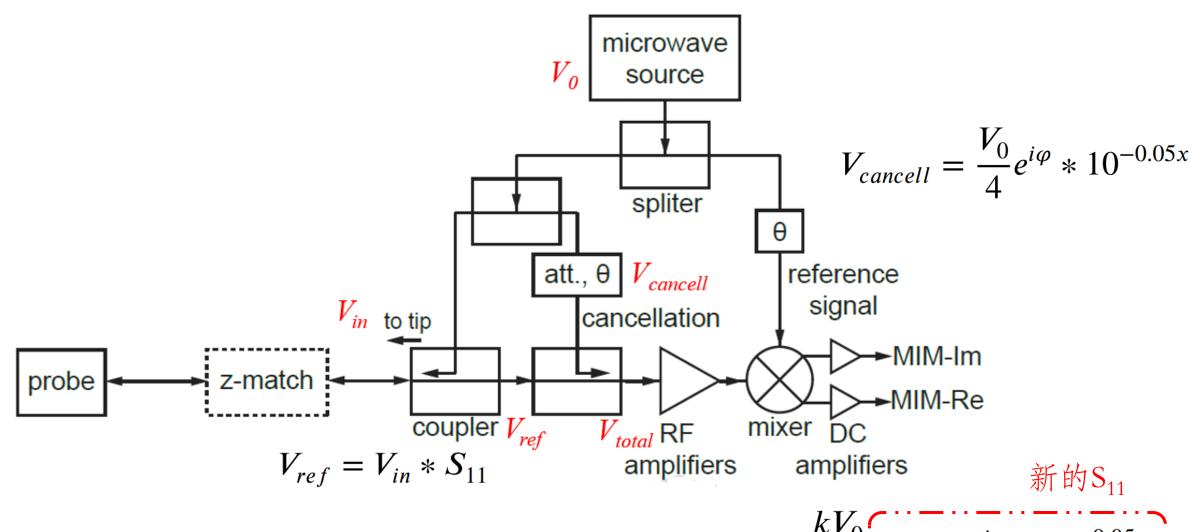
共振峰对样品电阻的响应



Amplitude vs R variation frequency/GHz Rsample/kOhm 峰值关于Rs的变化关系



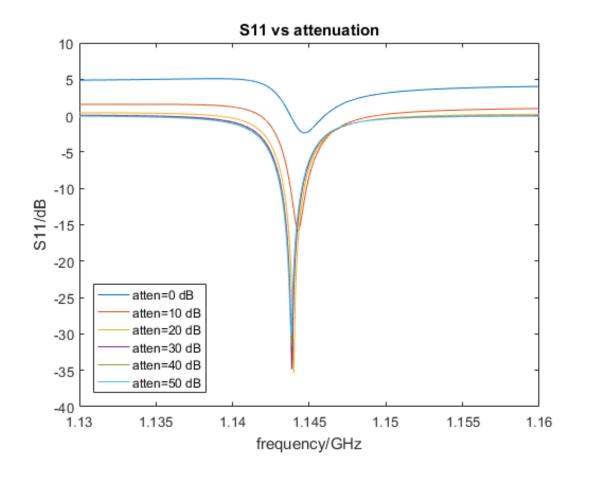
抵消(Cancellation)的实现

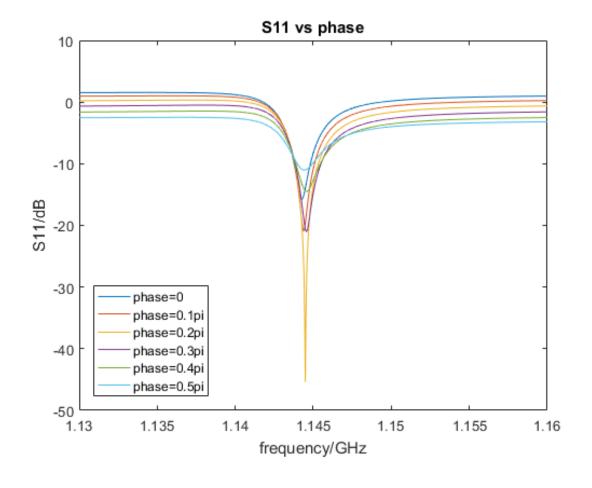


$$V_{total} = k * V_{cancell} + V_{ref} = \frac{kV_0}{4} (S_{11} + e^{i\varphi} * 10^{-0.05x})$$



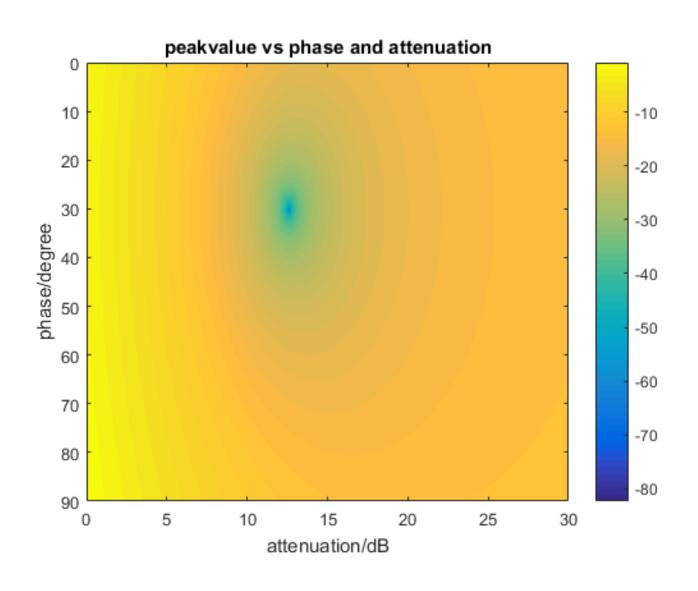
抵消后共振峰与x和φ的依赖关系





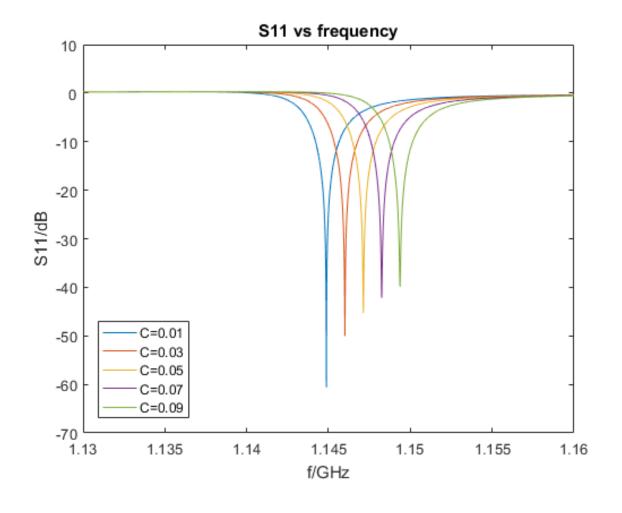


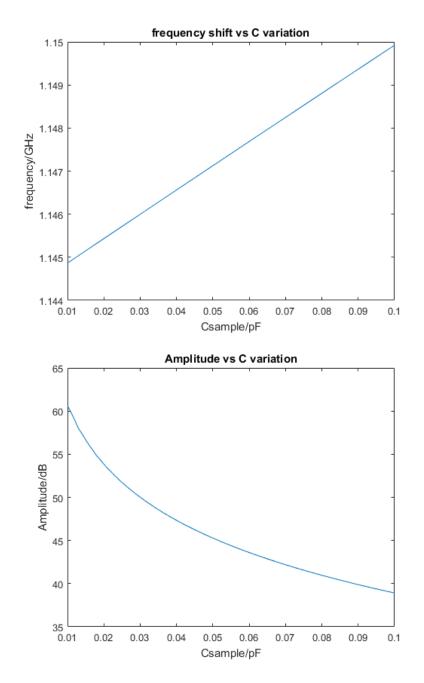
抵消后共振峰与x和φ的二维热图





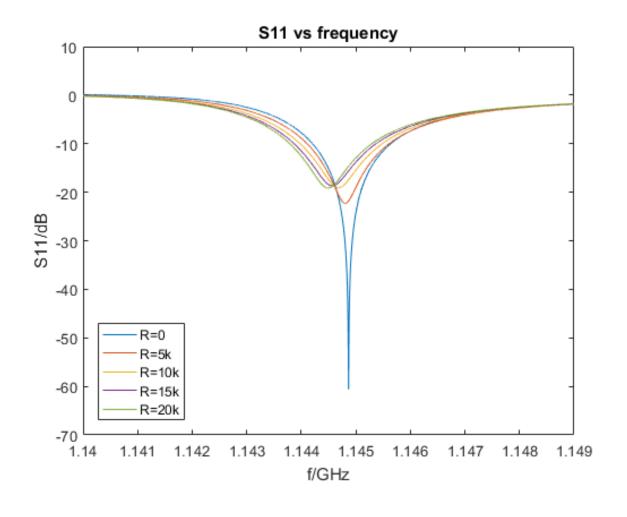
抵消后共振峰随样品电容的变化

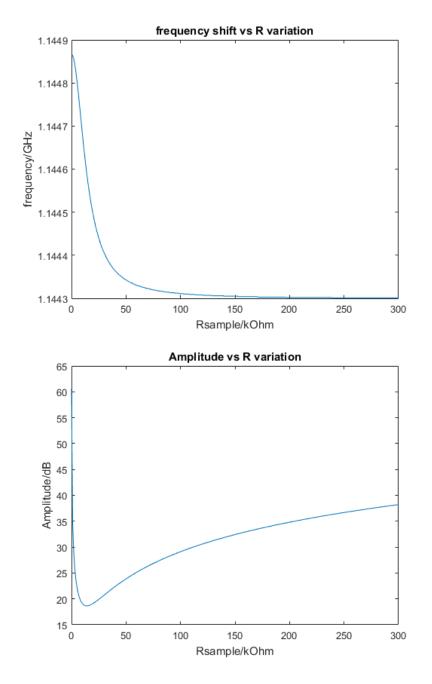




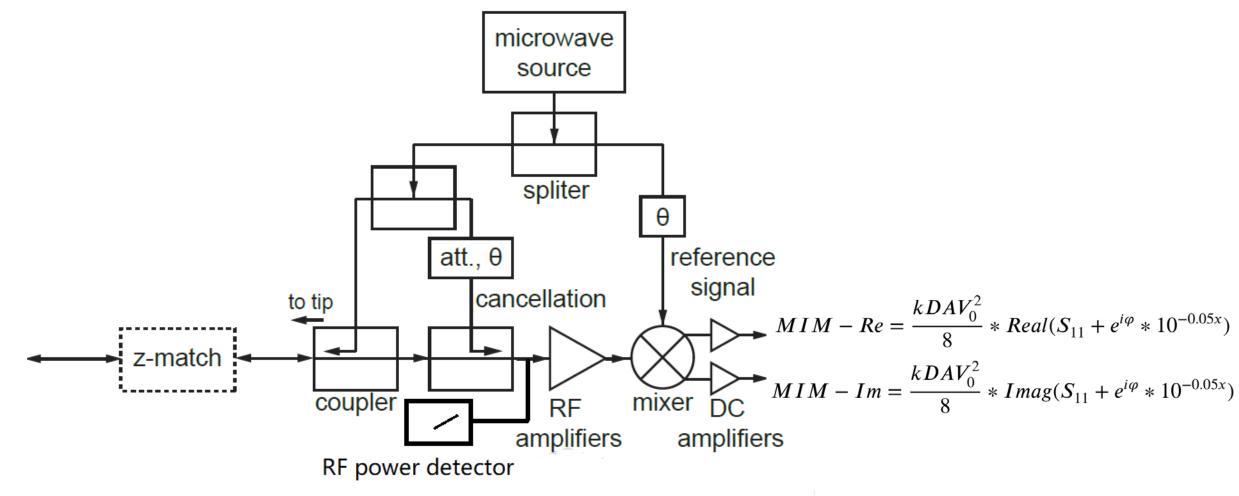


抵消后共振峰随样品电阻的变化





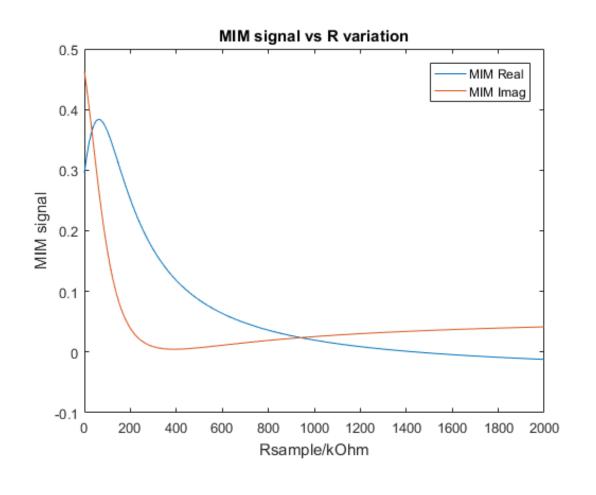
MIM 信号的计算

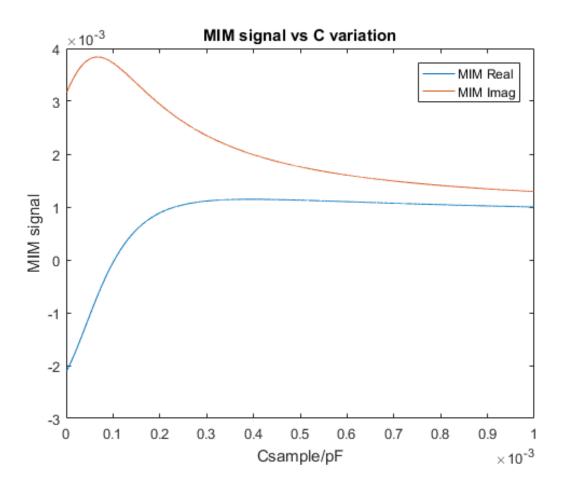


$$V_{total} = kA * V_{cancell} + V_{ref} = \frac{kAV_0}{4}(S_{11} + e^{i\varphi} * 10^{-0.05x})$$



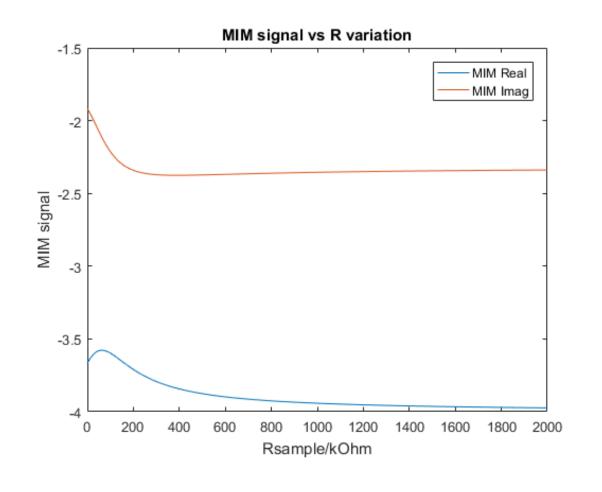
抵消后MIM信号关于样品电阻、电容的变化图

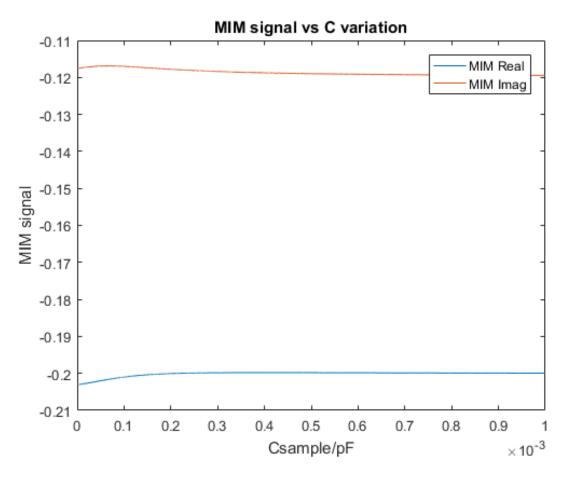




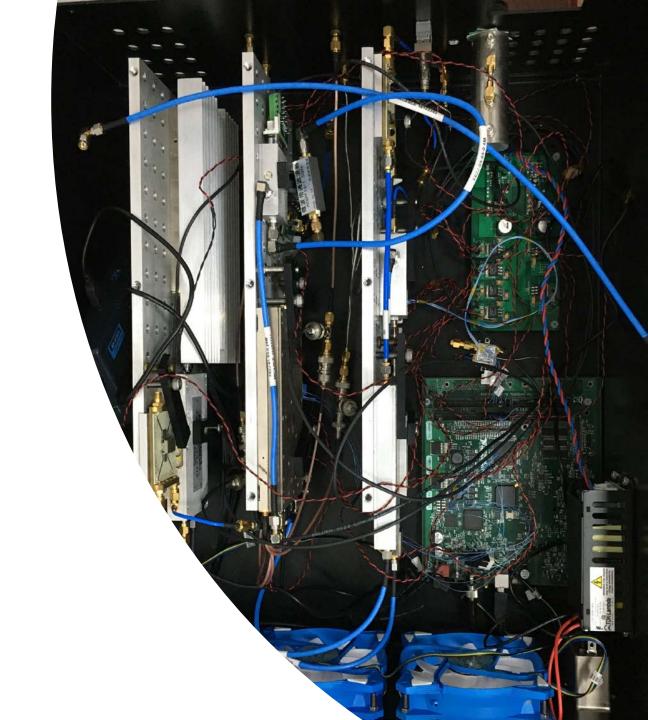


无抵消MIM 信号关于样品电阻、电容的变化图





- 微波电路基础
- 微波探测原理
- 微波阻抗显微系统





微波分辨原理

传播波 —— 隐失波

- 实部虚部高对比度
- 非接触,非破坏
- 长波长,亚表面探测

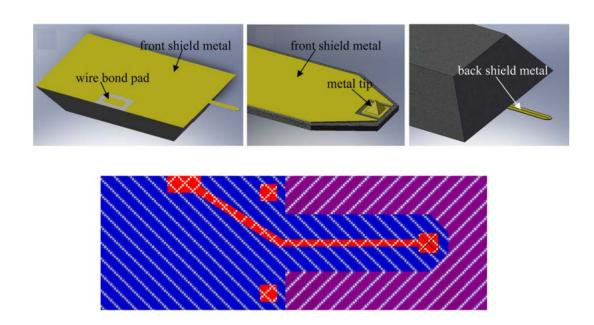
量子的 —— 经典的

$$k_0^2 = \omega^2 \epsilon_0 (\epsilon' + \epsilon'') \mu$$

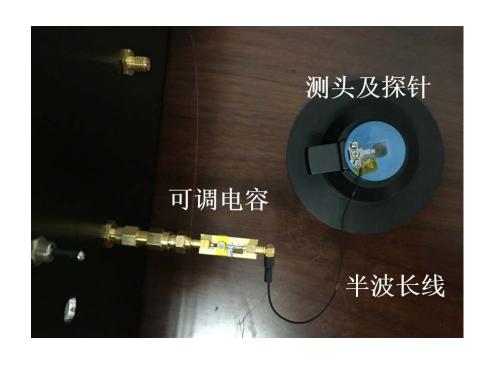
$$k_0^2 = \omega^2 \epsilon_0 (\epsilon' + i \frac{\sigma}{\omega \epsilon_0}) \mu$$



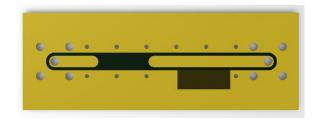
微波显微测头



扫描微波导电探针 SMIM150-G5 示意图



共振匹配单元的实现





微波显微测头

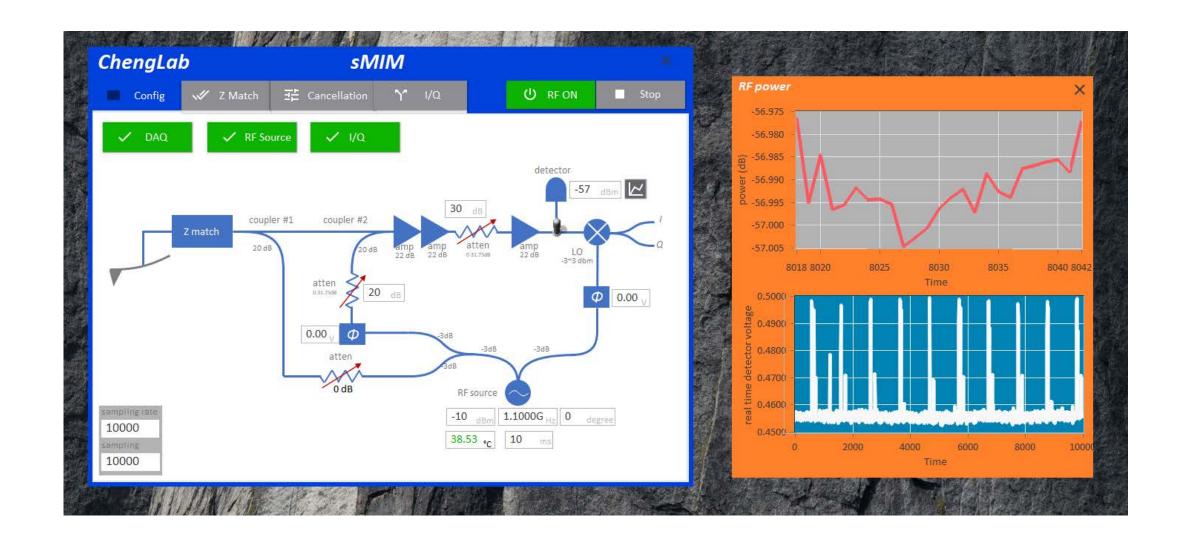




bond pad 直接连接至半波长线的内芯

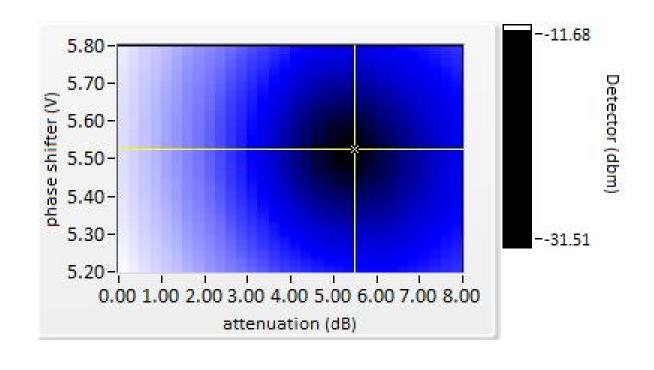


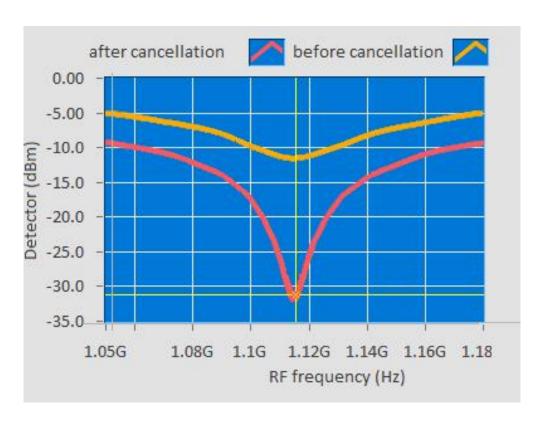
LabVieW控制程序界面





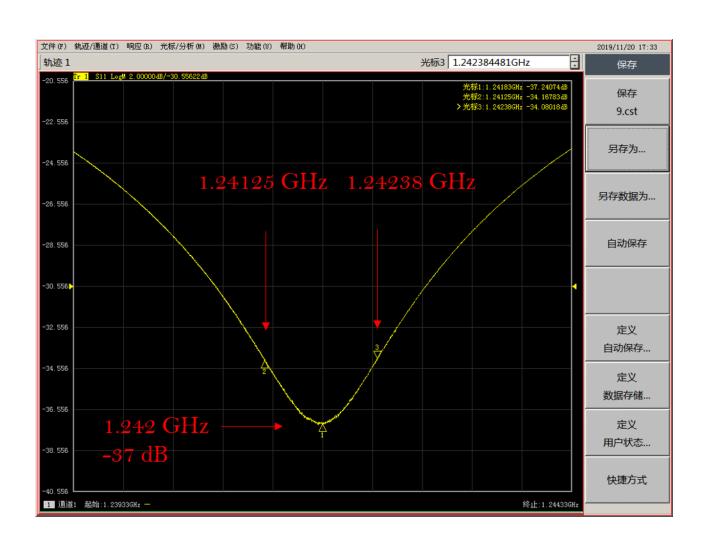
LabVieW控制抵消过程







实际测试共振匹配单元



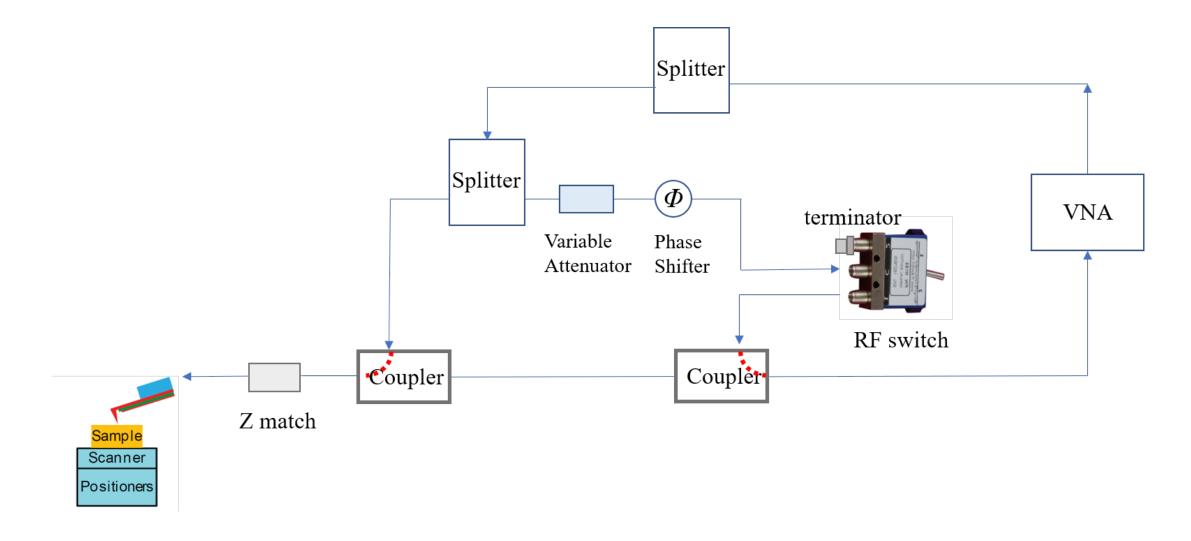
f = 1.242 GHz

 $\Delta f = 1.13 \text{ MHz}$

 $Q = f/\Delta f = 1100$

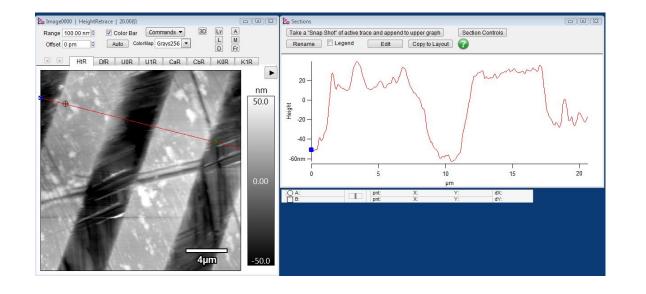


网络分析仪测试电路

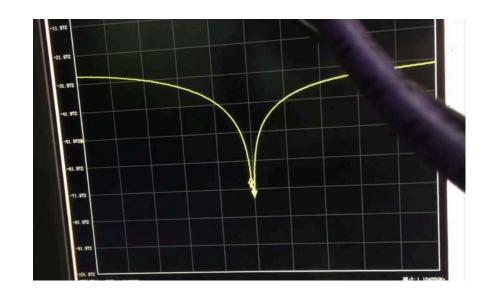


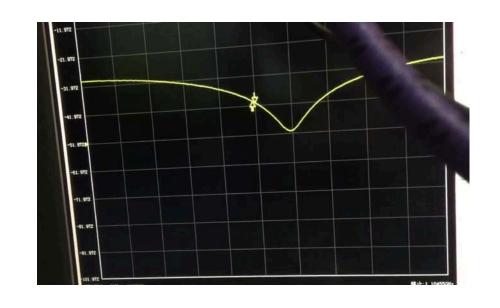


金属条带样品扫描



起伏约50 nm

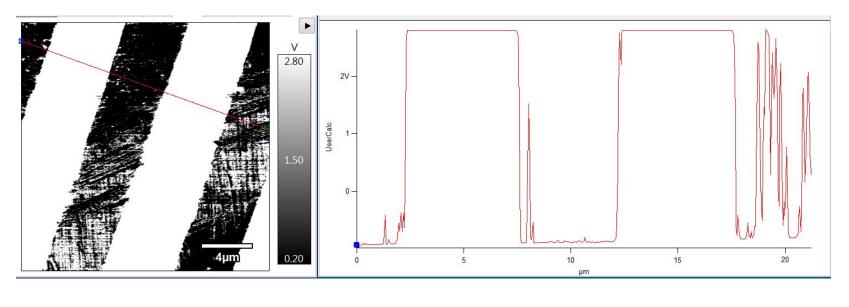


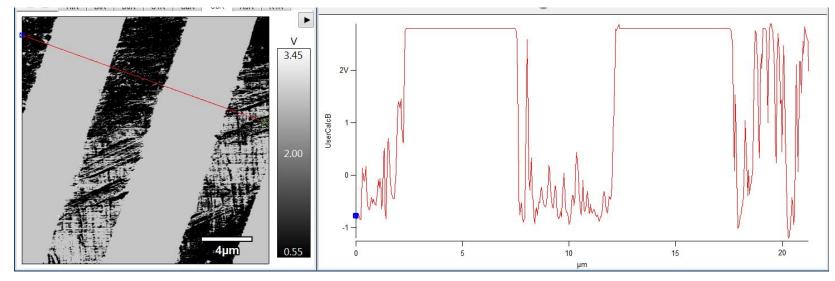


绝缘区域导电区域



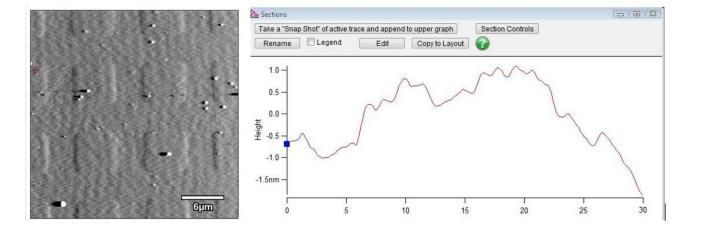
金属条带样品扫描



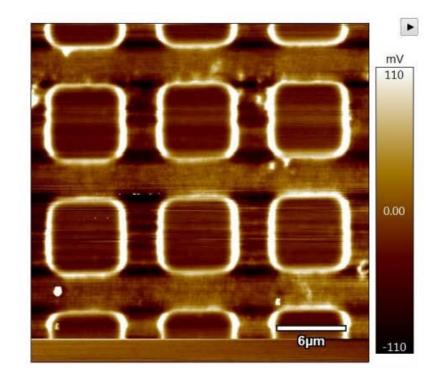


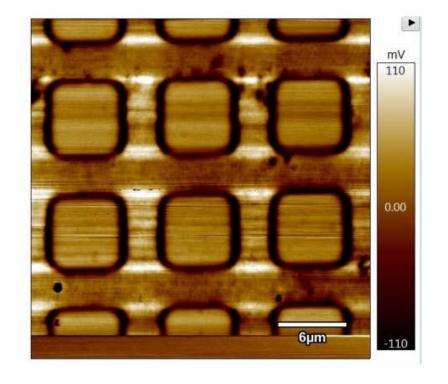


硅掺杂样品扫描



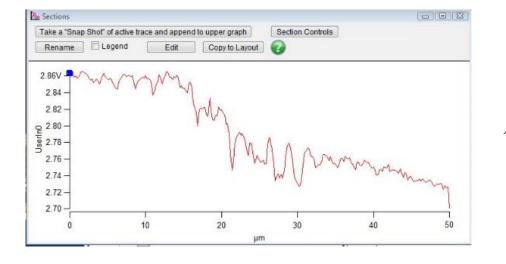
起伏约2 nm



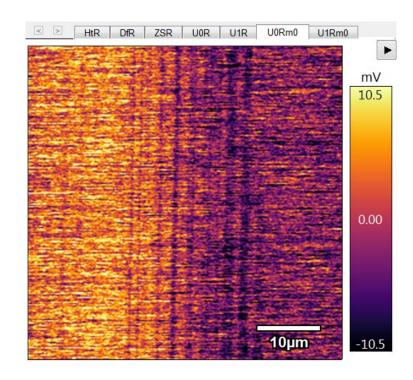


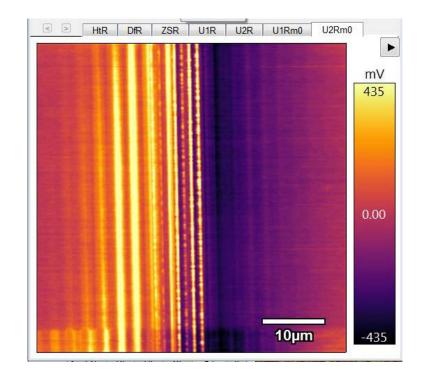


IFX掺杂样品扫描



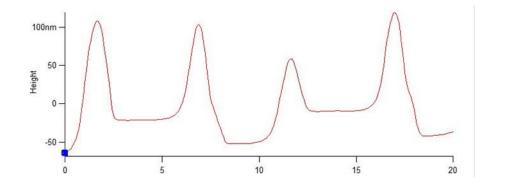
信号截面

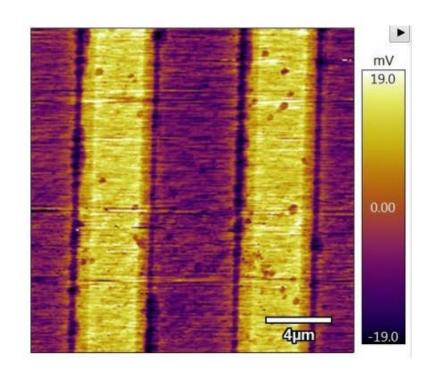


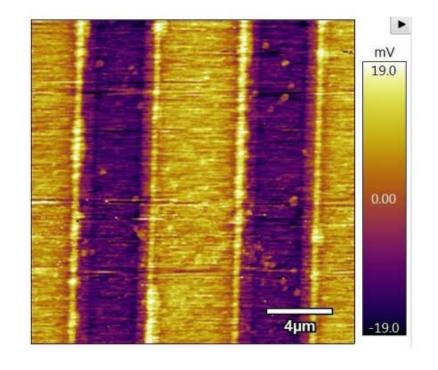




埋在绝缘体下方的金属条带样品扫描

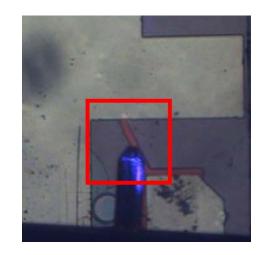


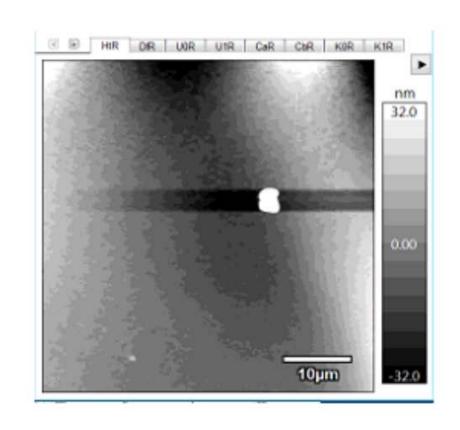


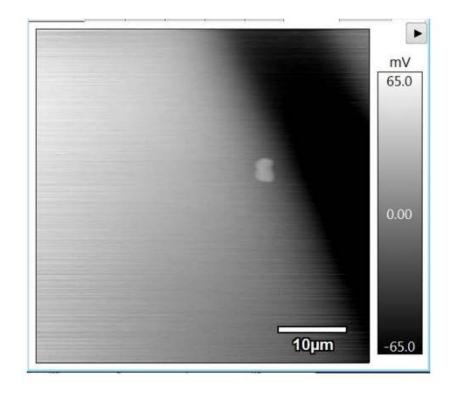




氮化硅下方的 Pt 对应 MIM 扫描信号

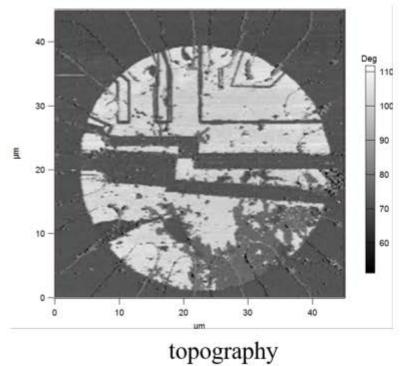


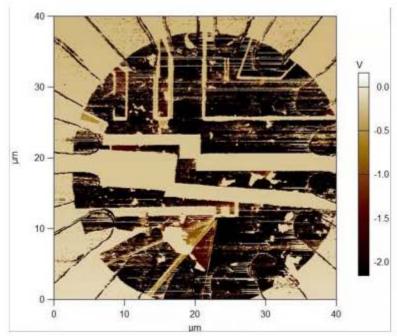




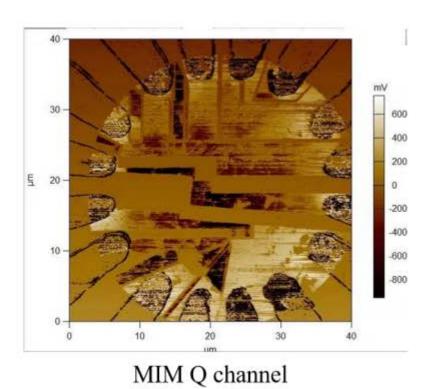


扫描单层导电石墨烯图像





MIM I channel





扫描 LaAlO₃/SrTiO₃ 界面处导电纳米线的图像

